**Abstract:** Garnet crystals possess many properties that are desirable in laser host materials, e.g., they are suitable for diode laser (LD) pumping, stable, hard, optically isotropic, and have good thermal conductivity, permitting laser operation at high average power levels. Recently, a new garnet material, GYSGG, was developed by replacing some of the yttrium ions (Y^{3+}) with gadolinium ions (Gd^{3+}) in YSGG, demonstrating great potential as a laser host material. GYSGG crystals doped with trivalent neodymium ion (Nd^{3+}) and erbium ions (Er^{3+}) were successfully grown for laser generation in the near- and mid-infrared range, with some of the laser performances reaching the level of mature laser gain media. This paper gives an overview of the achievements made in Nd^{3+}- and Er^{3+}-doped GYSGG lasers at different wavelength ranges. Additionally, full descriptions on Q-switching, mode-locking and wavelength-selecting methods for Nd:GYSGG, and the mechanisms of power scaling by co-doping sensitizers and deactivators in Er:GYSGG, are given. It is expected that this review will help researchers from related areas to quickly gain an understanding of these laser materials and promotes their commercialization and applications.

**Keywords:** Nd:GYSGG; Er:GYSGG; garnet laser crystal; solid-state laser; diode pumping; laser performance; radiation resistant

**1. Introduction**

Garnet crystals doped with the trivalent neodymium ion (Nd^{3+}) are regarded as the best solid-state laser materials, due to their good physical characteristics and laser performance, as well as the convenience of diode laser (LD) pumping around 808 nm. Nd:YAG, Nd:GGG, Nd:GGG and Nd:YSGG are several representatives [1–3]. From the view of industrialization, Nd:YAG is the most famous and successful type of Nd^{3+} doped garnet crystal to date in almost all application areas such as laser machining, display, medicine, scientific research, and military. Recently, however, a new garnet material, Nd:GYSGG, has been developed by replacing some of the yttrium ions (Y^{3+}) with gadolinium ions (Gd^{3+}) in Nd:YSGG. The material was successfully grown in the Anhui Institute of Optics and Fine Mechanics, Chinese Academy of Sciences [4–6]. The effective segregation coefficient of Nd^{3+} in GYSGG is much larger than that in YAG, and thus high-quality Nd:GYSGG bulk crystals with high doping concentration are much easier to grow than those of Nd:YAG using the conventional Czochralski method. Nd:GYSGG crystals with a diameter larger than 120 mm have been produced. The physicochemical and spectroscopic properties of Nd:GYSGG indicate prospective high-power laser operation. A comparison of the main physical and optical properties of Nd:YAG and Nd:GYSGG with doping concentration around 1.1 at% is given in Table 1.
Table 1. Comparison of main physical and optical properties of Nd:YAG and Nd:GYSGG [4–7].

<table>
<thead>
<tr>
<th>Property</th>
<th>Nd:YAG</th>
<th>Nd:GYSGG</th>
</tr>
</thead>
<tbody>
<tr>
<td>Effective segregation coefficient of Nd(^{3+})</td>
<td>0.1–0.2</td>
<td>0.598</td>
</tr>
<tr>
<td>Mohs hardness</td>
<td>8.5</td>
<td>6.55</td>
</tr>
<tr>
<td>Density (g/cm(^3))</td>
<td>4.56</td>
<td>5.62</td>
</tr>
<tr>
<td>Thermal conductivity (W cm(^{-1})K(^{-1}))</td>
<td>14</td>
<td>4.33</td>
</tr>
<tr>
<td>Refractive index at 1.0 µm</td>
<td>1.82</td>
<td>1.96</td>
</tr>
<tr>
<td>Absorption bandwidth around 808 nm (nm)</td>
<td>2–3</td>
<td>7</td>
</tr>
<tr>
<td>Absorption coefficient around 808 nm (cm(^{-1}))</td>
<td>3–8</td>
<td>4.9</td>
</tr>
<tr>
<td>Fluorescence lifetime (µs)</td>
<td>230</td>
<td>221</td>
</tr>
<tr>
<td>Emission linewidth (nm) around 1.06 µm</td>
<td>0.45</td>
<td>4.95</td>
</tr>
<tr>
<td>Stimulated emission cross-section for (^{4})(^{F}<em>{3/2})→^{4}(^{I}</em>{11/2}) transition (10(^{-19}) cm(^2))</td>
<td>2.8</td>
<td>1.5</td>
</tr>
</tbody>
</table>

Besides the attractive properties of Nd:GYSGG for laser operation, experimental results also show that it has good radiation resistance [5], making it promising in applications in environments with ionizing radiation. Great attention has been paid to the laser performance of this material during the past decade. Continuous-wave (CW), Q-switched and mode-locked Nd:GYSGG lasers emitting wavelengths around 1.06 µm and 1.1 µm from the \(^{4}\(^{F}_{3/2}\)→^{4}\(^{I}_{11/2}\) transition have been developed to achieve high-power operation. The \(^{4}\(^{F}_{3/2}\)→^{4}\(^{I}_{13/2}\) transition enabling 1.3 µm and 1.4 µm lasers and the \(^{4}\(^{F}_{3/2}\)→^{4}\(^{I}_{9/2}\) transition enabling 0.9 µm lasers, have also been investigated. Due to the energy-level Stark splitting in the disordered Nd:GYSGG crystal, multiple laser wavelengths can be generated individually or simultaneously. Efficient nonlinear frequency conversion using Nd:GYSGG lasers as the fundamental wave to pump optical parametric oscillators (OPOs), and Raman lasers operating in the 1.5–1.6 µm eye-safe range, have been realized.

On the other hand, trivalent erbium ion (Er\(^{3+}\))-doped garnet crystals, such as Er:YAG and Er:YSGG, can directly give 2.7–3 µm mid-infrared laser radiation through the \(^{4}\(^{I}_{11/2}\)→^{4}\(^{I}_{13/2}\) transition [4]. Such radiation has great value in medicine, as this is the strongest water absorption band throughout the optical regime. For the same purpose, and following a similar approach to Nd:GYSGG, another new category of laser materials—the Er:GYSGG crystals—have been grown by the Czochralski method. These crystals possess the main physical and anti-radiation merits of Nd:GYSGG [8]. Different ions can be used as sensitizers and deactivators to enhance the LD-to-laser conversion efficiency and overcome the self-terminating “bottleneck” effect. As a result, efficient mid-infrared laser generation has been obtained by pumping with LDs around 970 nm.

Several as-grown crystal photographs of Nd\(^{3+}\) and Er\(^{3+}\) doped GYSGG crystals are shown in Figure 1. The details of the crystal growth (synthesis, single-crystal growth, doping concentration, segregation coefficient, etc.), physical properties (density, lattice parameter, refractive index, thermal conductivity, etc.), mechanical properties (hardness, fracture toughness, brittleness index, yield strength, etc.), spectral properties (absorption and emission spectrum, Judd–Ofelt analysis, energy-level transition, fluorescence lifetime, stimulated cross-section, etc.) and the radiation resistance of the Nd:GYSGG crystals have been studied comprehensively in previous works [5–7]. Some other important characteristics of Nd:GYSGG, such as the dependence of the fluorescence lifetime and non-radiative decay rate on the Nd\(^{3+}\) concentration, the dependence of the refractive index, nonlinear refractive index, elastic constants, and the thermal stress resistance on temperature, are still waiting for further research. The properties of Er:GYSGG crystals and sensitizer/deactivator-doped Er:GYSGG crystals are not as fully investigated as Nd:GYSGG, although some feedback on the crystal growth and main spectral properties (absorption and emission spectra, energy transfer diagram, etc.) is available in several works published in the past few years [8–11].
Considering the maturity of the aforementioned crystals, the related data integrity, as well as the orientation of this paper, this review is focused on the performance of Nd$^{3+}$- and Er$^{3+}$-doped GYSGG lasers, and which is different from the representative review paper concentrating on the characterization of Nd:GSGG crystals [12]. This paper summarizes the development of Nd$^{3+}$- and Er$^{3+}$-doped GYSGG lasers at different wavelengths under various operations. The basics and methods for improving the laser performance are also demonstrated and discussed. A comparison of main performance indicators with the common garnet materials indicates that Nd$^{3+}$ and Er$^{3+}$ doped GYSGG crystals are good candidates for solid-state laser media for efficient high-power laser operation at several wavelength ranges. It is expected that this review will help researchers from related areas to learn about this material and promote its commercialization and application, including applications in space and environments with ionizing radiation.

2. Laser Performance of Nd$^{3+}$-Doped GYSGG

The absorption spectrum of Nd:GYSGG was measured by a Perkin Elmer Lambda 900 ultraviolet-visible-near infrared (UV/VIS/NIR) Spectrometer (PerkinElmer, Inc., Waltham, MA, USA), as shown in Figure 2a. There are eight absorption bands in the 400–1000 nm range originated from the ground state $^{4}F_{9/2}$ and the peak is located at 808 nm. The Judd–Ofelt method for the calculation of oscillation strength, as well as the estimation of spectrum parameters for the radiative transitions (fluorescence branching ratio, transition rate and lifetime) are given in [6]. The stimulated emission cross-section was obtained by the Füchtbauer–Ladenburg (F-L) equation based on the fluorescence parameters [13], as shown in Figure 2(b). Five potential major laser emission bands can be acquired located around 0.94 μm ($^{4}F_{3/2}$→$^{4}I_{9/2}$), 1.06 μm ($^{4}F_{3/2}$→$^{4}I_{11/2}$), 1.1 μm ($^{4}F_{3/2}$→$^{4}I_{11/2}$), 1.32 μm ($^{4}F_{3/2}$→$^{4}I_{13/2}$), and 1.42 μm ($^{4}F_{3/2}$→$^{4}I_{13/2}$). Similar to other Nd$^{3+}$-doped lasers, the gain at around 1.06 μm is the strongest. The stimulated emission cross-section of the $^{4}F_{3/2}$→$^{4}I_{11/2}$ transition at 1.06 μm was found to be $1.5 \times 10^{-19}$ cm$^2$, which was also verified using both the laser efficiency comparison method and the threshold formula method [14].
The properties of these premature materials, graphene, and tungsten disulfide (WS$_2$) have been extensively studied with various saturable absorbers. Benefiting from the absorption spectrum of Nd:GYSGG laser crystals, the oscillation peak is located at around 1.06 μm, where two lines, at 1058 nm and 1062 nm, possess comparable emission cross sections.

Figure 1. Photographs of as-grown Nd$^{3+}$- and Er$^{3+}$-doped GYSGG crystals: (a) Nd$^{3+}$, (b) Er$^{3+}$.

Figure 2. The room-temperature absorption coefficient (400–1000 nm) and stimulated emission cross-section (850–1450 nm) of a 1.1 at% doped Nd:GYSGG crystal [5].

2.1. Nd:GYSGG Laser Operating in the 1.05–1.11 μm Range

The feasible laser wavelengths from the $^4F_{3/2} \rightarrow ^4I_{11/2}$ transition are spread over a large range from 1.05 to 1.11 μm. Details of the energy levels are shown in Figure 3. The oscillation peak is located at around 1.06 μm, where two lines, at 1058 nm and 1062 nm, possess comparable emission cross sections.

The first demonstration of an Nd:GYSGG laser was in 2011 [15]. Using a typical linear diode-end-pumping cavity, as shown in Figure 4, stable CW dual-wavelength laser operation at 1058.4 and 1061.5 nm was achieved with a 1.1 at% doped Nd:GYSGG crystal. The maximum output power was 10.1 W, corresponding to a slope efficiency of nearly 60%, which was among the best laser performances with mature garnet laser crystals like Nd:YAG. Using an acousto-optic (AO) Q-switch, the maximum single-pulse energy and peak power of the Nd:GYSGG laser reached 277 μJ and 4.6 kW, respectively, with a pulse width around 60 ns. Such a dual-wavelength pulsed laser could be used in terahertz generation through the nonlinear optical difference frequency generation (DFG) method.

Figure 3. Energy-level transitions of $^4F_{3/2} \rightarrow ^4I_{11/2}$ excited at 808 nm for Nd:GYSGG.

Figure 4. Experimental scheme of the diode-end-pumped Nd:GYSGG laser. LD: diode laser.
In order to compress laser pulse width and enhance peak power, passively Q-switched Nd:GYSGG lasers have been extensively studied with various saturable absorbers. Benefiting from a much shorter cavity than in active Q-switching, Zhang et al. obtained short pulses, down to 6.6 ns, using a Cr:YAG saturable absorber, and a peak power of up to 9.97 kW [16]. Since then, graphene oxide [17], tungsten disulfide (WS₂) [18], 2D-material (SnSe₂) [19], gold nano-triangles [20], and TiS₂, MoS₂, and WS₂/Sb₂Te₃ mixed nanosheets [21] have been investigated for use in passive Q-switching. However, the poor physical and optical properties of these premature materials have severely limited their performance for loss modulation in the Nd:GYSGG laser cavity. Song et al. also observed dual-wavelength self-Q-switching in Nd:GYSGG [22], which might be caused by the nonlinear loss induced by the time-dependent thermal lensing effect in the laser crystal.

As the emission bandwidth of Nd:GYSGG is much broader than that of Nd:YAG, Nd:GYSGG has distinct advantages in generating ultrashort laser pulses. Zhang et al. realized CW mode-locked Nd:GYSGG laser operation at 1061.5 nm using a semiconductor saturable absorber mirror (SESAM) by employing an experimental scheme as shown in Figure 5 [23]. The maximum average output power reached 1.27 W, corresponding to a slope efficiency of 18.9%. At a repetition rate of 42 MHz, the pulse width was 3.1 ps, which is much shorter than that of a typical mode-locked Nd:YAG laser, thus fully exhibiting the excellent laser performance of Nd:GYSGG for mode-locked operation. Song et al. employed graphene oxide as the saturable absorber, achieving a passively Q-switched mode-locked Nd:GYSGG laser with two output wavelengths at 1057 and 1060 nm. The pulse duration was 441 ps at a repetition rate of 100 MHz [24].

![Figure 5. Schematic diagram of a mode-locking Nd:GYSGG laser [23]. SESAM: semiconductor saturable absorber mirror.](image)

Benefiting from the diversity of upper and lower energy-level Stark splitting, laser transitions that are impossible with common garnet laser crystals can be realized with disordered Nd:GYSGG crystals. An example of this is the 1053 nm laser line which is close to the σ-polarized wavelength generated in Nd:YLF. Although the stimulated emission cross-section was much smaller (1/5 of that at 1061.5 nm), it was possible to achieve pure CW 1053 nm laser generation in Nd:GYSGG by optimizing the cavity mirror coatings to suppress the oscillation at 1058.4 and 1061.5 nm [25]. The maximum output power was 4.17 W and the optical–optical conversion efficiency reached 33.9%. For passive Q-switching with a Cr:YAG absorber, the gain at 1058.4 nm was high enough to overcome its high loss, leading to stable dual-wavelength oscillation at 1052.8 and 1058.4 nm. The single-pulse energy was up to 172.1 μJ with the peak power of 26.1 kW, when the pulse width was 6.6 ns at 4.3 kHz. Such a Q-switched dual-wavelength laser with high peak power provides a good pump source to generate terahertz waves at 1.53 THz via the nonlinear DFG process.

As shown in Figure 2b, an obvious emission band of Nd:GYSGG is located around 1.1 μm, which also comes from the \(^4\)F\(_{3/2} \rightarrow \)\(^4\)I\(_{11/2}\) transition. The precondition for high-power laser operation in this band is that the high gain around 1.06 μm should be effectively restrained. Shen et al. reported the first demonstration of an Nd:GYSGG laser operating at 1104 nm with a \(T = 6.6\%\) output coupler, which delivered a CW laser output power of 4.7 W, corresponding to a conversion efficiency of 24.6% and slope efficiency of 37% [26]. Using a high-Q cavity (\(T = 1.2\%\)–1.3% in the 1105–1110 nm range), Lin et al. realized simultaneous oscillation of three wavelengths at 1105, 1107, and 1110 nm [27].
Single-wavelength operation at 1110 nm reached 1.56 W with a T = 4.5% output coupler [27]. According to the solution of rate equations for Q-switched solid-state lasers [4, 28, 29], tremendous population inversion can be accumulated before the Q switch opens, which produces much higher gain than the CW operation. Thus, in order to achieve Q-switched 1.1 μm lasers, the cavity loss at 1.06 μm should be sufficiently high to suppress its oscillation in Q-switching mode and the optimal coupling efficiency at 1.1 μm should be higher than the CW operation. In a preliminary study, Dun et al. reported a passively Q-switched Nd:GYSGG laser at 1111.4 nm [30]. The saturable absorber was made of gold nanorods and the output couplers had transmissions of 5.7 and 9%, which realized a maximum output power, pulse repetition rate, and pulse width of 125 mW, 120 kHz and 550.6 ns, respectively.

2.2. Nd:GYSGG Laser Operating in the 1.3–1.45 μm Range

Referring to Figure 2b, there are two separated parts from the \(^{4}F_{3/2} \rightarrow ^{4}I_{13/2}\) transition—one is in the 1.3–1.35 μm range and the other is in the 1.4–1.43 μm range, with possible emission wavelengths shown in Figure 6. Apparently, the stimulated emission cross-section for the 1.3–1.35 μm range is much higher, where the peak is located at 1336 nm. However, to achieve the 1.4 μm laser operation, stringent requirements should be fulfilled, such as a high-finesse cavity and good suppression of the 1.3 μm laser oscillation.

![Figure 6. Energy-level transitions of \(^{4}F_{3/2} \rightarrow ^{4}I_{13/2}\) excited at 808 nm for Nd:GYSGG.](image_url)

The first Nd:GYSGG laser in the 1.3–1.35 μm wavelength range was reported in 2012 [31]. Using a diode-end-pumped plane-parallel cavity with different out-coupling efficiencies of 8.4 and 6.0%, single-wavelength operation at 1336 nm and dual-wavelength operation at 1321/1336 nm with a minor wavelength at 1330 nm were achieved with variable power proportions according to the pump intensity. The maximum output power at 1336 nm was 1.98 W with 13.5 W incident LD pump power, corresponding to a conversion efficiency of 14.7%. Later, the laser cavity was optimized into a plano-concave one, and the maximum output power was increased to 2.5 W at 1336 nm, corresponding to a conversion efficiency of 18.5% [32].

In order to achieve 1.4 μm laser oscillation, the output coupler was designed to have high transmission loss (T > 60%) in the 1.3–1.38 μm range, and the 1.4 μm cavity loss was minimized to accumulate sufficient gain. With an output coupler that had transmissions of T = 1.9% and T = 1.1% at 1404 nm and 1424 nm, respectively, 250 mW output power was obtained when the absorbed pump power was 9.1 W [32]. The pump thresholds for both the 1404 nm and 1424 nm lasers were around 1 W. The power of the 1424 nm laser grew faster while increasing the pump power, during which a quite weak 1415 nm laser line emerged. The transmissions of the second output coupler were T = 7.9% at 1404 nm and T = 4.3% at 1424 nm, which successfully eliminated the oscillations at 1404 nm and 1415 nm and realized pure 1424 nm laser emission. The maximum power at 1424 nm reached 707 mW with a 10.4 W absorbed pump power, corresponding to a conversion efficiency of 6.8% and slope efficiency of 9.4%. Since above 1.4 μm the laser wavelength enters the “eye-safe” band, the
1.4 µm Nd:GYSGG laser provides an option for lidar and range-finding applications, especially in environments with ionizing radiation.

Although AO Q-switching is a conventional and preferred approach for generating stable laser pulses, passive Q-switching is sometimes superior due to its narrower pulse width and higher peak power with a much shorter cavity. As an excellent candidate for saturable absorbers working in the 1.3–1.4 µm range, V\(^{3+}\):YAG has good optical and physical properties. Its absorption cross-section for the ground state is \(7.2 \times 10^{-18}\) cm\(^2\) at 1.34 µm, while it is much lower for the excited state, making it easy to be bleached. Song et al. reported a 1331 nm V\(^{3+}\):YAG Q-switched Nd:GYSGG laser delivering an average power of 251 mW [33]. The minimum pulse width was 23.9 ns at 11 kHz, corresponding to a peak power of 954 W. Lin et al. investigated another saturable absorber for passively Q-switching, Co:MgAl\(_2\)O\(_4\) [34], whose absorption peak was close to 1520 nm and which is mostly used for lasers in the eye-safe wavelength region. The Co:MgAl\(_2\)O\(_4\) Q-switched Nd:GYSGG laser at 1331 nm could give an output power of 225 mW, with a pulse width of 20.5 ns and a peak power of 1.3 kW.

A narrow-linewidth (sub-pm level) AO Q-switched Nd:GYSGG laser generating nanosecond pulses at 1336.6 nm was realized by Li et al. in a ring cavity [35], as shown in Figure 7. Using a birefringent filter and two etalons with different thicknesses for wavelength selection and linewidth compression, a linewidth of 0.85 pm was achieved with a macropulse output energy of 36.7 mJ at 10 Hz. At a pulse repetition rate of 80 Hz, the width of the micropulse was 300 ns and the peak power reached 15.3 kW. The maximum output macropulse energy at 1336.0 nm reached 365 mJ when the LD pump pulse energy was 4.23 J, with a pump threshold of 1.23 J and a conversion efficiency of 8.62%. The M\(^2\) factors of the narrow-linewidth laser in both orthogonal directions were less than 1.5, indicating that it was a good Gaussian fundamental transverse mode. The wavelength stability was also kept at a good level, with a fluctuation of less than 2 pm for 20 minutes. Applications of such a narrow-linewidth laser in optical frequency standard through its eighth harmonics (167.079 nm) in the deep ultraviolet range were also proposed.

![Figure 7. Experimental setup of the narrow-linewidth pulsed Nd:GYSGG ring laser at 1336 nm [35].](image)

2.3. Nd:GYSGG Laser Operating in the 0.9–0.95 µm Range

The \(4F_{3/2} \rightarrow 4I_{9/2}\) transition of Nd\(^{3+}\)-doped lasers provides a straightforward method for high-brightness laser sources in the 0.9–0.95 µm range, which are attractive in pumping Yb\(^{3+}\)-doped laser gain media (e.g., Yb:YAG), water vapor absorption lidar, and the generation of blue laser through frequency doubling. However, as quasi-three-level systems, the power scaling in this range is usually limited. Besides taking measures to reduce reabsorption loss, a well-designed cavity is also necessary to achieve laser oscillation with high output power and efficiency. The emission cross-section of the \(4F_{3/2} \rightarrow 4I_{9/2}\) transition in Nd:GYSGG is slightly lower than the \(4F_{3/2} \rightarrow 4I_{11/2}\) transition around 1.06 µm, making it a good candidate for 0.9 µm lasers, as shown in Figure 2b. Two distinct peaks are located in this range, one at 933 nm and the other at 937 nm. The weaker former transition was from R2 to Z5 and the stronger latter one was from R1 to Z5, with both fluorescence linewidths being around 1.6 nm.

The first quasi-three-level Nd:GYSGG laser was reported in 2013 [36]. With a 1.1 at% doped Nd:GYSGG crystal, the CW output power at 937 nm was 0.8 W using a simple plano-concave cavity
at 0 °C working temperature. The conversion efficiency and slope efficiency reached 9.8% and 15.3%, respectively. Significant power reduction and threshold increase was observed if the working temperature was increased, due to the serious reabsorption loss in the Nd:GYSGG crystal. In order to improve the output power, crystals that are longer and have a lower doping concentration should be favorable, since they can greatly alleviate the reabsorption and thermal effects inside the laser crystal. Other potential improvements are better cavity arrangement, mirror and crystal coatings, etc. Unfortunately, there have been few publications on the quasi-three-level Nd:GYSGG laser since 2013. Considering its large stimulated emission cross-section at 0.94 μm, high-power laser emission comparable to that with Nd:YAG in this band can be expected under optimal crystal growth and cavity design [37].

Cryogenic cooling has been extensively studied for scaling the power of quasi-three-level Yb\(^{3+}\), Ho\(^{3+}\), and Nd\(^{3+}\)-doped YAG lasers [38–40], demonstrating prominent benefits in reducing reabsorption loss, increasing emission cross-section, and improving the thermo-optical properties of the gain media. Recent results show that monolithic Nd:YAG lasers can deliver an output power of over 30 W at 946 nm under cryogenic cooling, corresponding to a slope efficiency of up to 78% [41], which provides an efficient method for scaling the power of a 937 nm Nd:GYSGG laser. On the other hand, the fact that the quasi-three-level laser performance in the 0.9–0.95 μm range is sensitive to working temperature can be effectively utilized. In a multiple-wavelength laser containing a laser line from the \(^{4}F_{3/2} \rightarrow ^{4}I_{9/2}\) transition (quasi-three-level system), its oscillation is restrained at the lasing at the other wavelengths (four-level systems) should be enhanced. This is due to the fact that all the laser wavelengths share the same upper level, and once the 0.9 μm laser is reabsorbed the population inversion is accumulated, bringing extra gain at the other wavelengths. Such a concept prompted a novel idea for power-ratio tunable dual/multiple-wavelength lasers via the adjustment of the working temperature. A successful implementation was demonstrated through a dual-band Nd:GYSGG laser at 0.94 μm and 1.06 μm [42]. As shown in Figure 8, the power ratio of the two bands could be stably and repeatably tuned at a large scale: the power proportion at 1.06 μm was tuned from 12.4 to 100% while the working temperature was increased from 2 to 20 °C under an incident pump power of 3.14 W.

![Figure 8](image)

**Figure 8.** Tunable 1.06 μm power ratio in a dual-band (0.94 μm and 1.06 μm) Nd:GYSGG laser achieved via changing the working temperature [42].

### 2.4. Nd:GYSGG Laser Performance: Summary

To summarize, the Nd:GYSGG laser performance at major oscillating wavelengths is shown in Table 2, with operation modes covering CW, Q-switched, and mode-locked. All the pump sources are LDs at 808 nm, and the average output power, single-pulse energy, and optical–optical conversion efficiency from LD to laser output are given in Table 2. Although the average output power and pulse energy are not as remarkable as those of Nd:YAG lasers, the maximum optical–optical conversion efficiency can reach around 55%, which is relatively impressive for diode-end-pumped solid-state lasers.

<table>
<thead>
<tr>
<th>Pump power (W)</th>
<th>μm</th>
<th>Power percentage (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Pump power = 3.14 W</td>
<td>0.94</td>
<td>100</td>
</tr>
<tr>
<td>Pump power = 4.49 W</td>
<td>1.06</td>
<td>100</td>
</tr>
<tr>
<td>Pump power = 5.48 W</td>
<td>0.94</td>
<td>100</td>
</tr>
<tr>
<td>Pump power = 6.78 W</td>
<td>1.06</td>
<td>100</td>
</tr>
</tbody>
</table>

Table 2
It should be noted that there are still serious barriers to improving the performance of Nd:GYSGG lasers, e.g., the lack of accurate modeling of rate equations to acquire the dynamics of population inversion and laser generation, and the lack of intensive analysis of the dominant energy transfer mechanisms. Under this premise, the doping concentration of Nd:GYSGG crystals can be optimized and better cavity design is straightforward, paving the way for high-power and efficient Nd:GYSGG lasers, especially for quasi-three-level laser systems. Further power and energy scaling can incorporate side-pumping or slab lasers, which allow a much higher incident pump power; however, these schemes have not yet been fully exploited. In particular, a much larger emission linewidth (4.95 nm) of Nd:GYSGG over Nd:YAG (0.45 nm), etc., has demonstrated great potential in ultrashort pulse generation. A concise comparison of the pulse durations for Nd:GYSGG and commonly used laser crystals for diode-end-pumped mode-locked lasers around 1.06 µm (which were all achieved with SESAMs) is given in Table 3.

**Table 2. Laser performance at major oscillating wavelengths of Nd:GYSGG.**

<table>
<thead>
<tr>
<th>Wavelength (nm)</th>
<th>Operation Mode</th>
<th>Pumping Scheme</th>
<th>Power/Energy</th>
<th>Efficiency</th>
<th>M² Factor</th>
</tr>
</thead>
<tbody>
<tr>
<td>937 [36]</td>
<td>CW</td>
<td>End</td>
<td>0.8 W</td>
<td>9.8%</td>
<td>—</td>
</tr>
<tr>
<td>1053 [25]</td>
<td>CW</td>
<td>End</td>
<td>4.17 W</td>
<td>33.9%</td>
<td>13</td>
</tr>
<tr>
<td>1053/1058 [25]</td>
<td>Q-switched</td>
<td>End</td>
<td>0.74 W/172 µJ</td>
<td>16.1%</td>
<td>—</td>
</tr>
<tr>
<td>1058/1061 [15]</td>
<td>CW</td>
<td>End</td>
<td>10.1 W</td>
<td>54.7%</td>
<td>2.8</td>
</tr>
<tr>
<td>1058/1061 [15]</td>
<td>Q-switched</td>
<td>End</td>
<td>2.77 W/277 µJ</td>
<td>24.3%</td>
<td>—</td>
</tr>
<tr>
<td>1061 [23]</td>
<td>Mode-locked</td>
<td>End</td>
<td>1.27 W</td>
<td>17.2%</td>
<td>—</td>
</tr>
<tr>
<td>1104 [26]</td>
<td>CW</td>
<td>End</td>
<td>4.7 W</td>
<td>24.6%</td>
<td>—</td>
</tr>
<tr>
<td>1110 [27]</td>
<td>CW</td>
<td>End</td>
<td>1.56 W</td>
<td>14.1%</td>
<td>—</td>
</tr>
<tr>
<td>1321/1336 [32]</td>
<td>CW</td>
<td>End</td>
<td>1.998 W</td>
<td>12.9%</td>
<td>1.2</td>
</tr>
<tr>
<td>1336 [32]</td>
<td>CW</td>
<td>End</td>
<td>2.5 W</td>
<td>18.5%</td>
<td>—</td>
</tr>
<tr>
<td>1336 [35]</td>
<td>Q-switched</td>
<td>Side</td>
<td>356 mJ</td>
<td>8.6%</td>
<td>1.4</td>
</tr>
<tr>
<td>1424 [32]</td>
<td>CW</td>
<td>End</td>
<td>0.707 W</td>
<td>6.8%</td>
<td>—</td>
</tr>
</tbody>
</table>

**Table 3. Comparison of emission linewidth and SESAM-mode-locked laser pulse duration around 1.06 µm between Nd:GYSGG and commonly used laser gain media.**

<table>
<thead>
<tr>
<th>Property</th>
<th>Nd:YAG</th>
<th>Nd:YVO₄</th>
<th>Nd:GdVO₄</th>
<th>Nd:GYSGG</th>
</tr>
</thead>
</table>

3. Laser Performance of Er⁴⁺-Doped GYSGG

3.1. Mid-Infrared Laser Performance of Er:GYSGG at 2.79 µm

High-quality Er:GYSGG crystals and their laser performance were firstly reported by the Anhui Institute of Optics and Fine Mechanics, Chinese Academy of Sciences, in 2013 [8]. The Er:GYSGG crystals were grown by the Czochralski method by replacing some of the Gd³⁺ ions with Y³⁺ in Er:GSGG, realizing a crystal size of approximately φ 25 mm × 100 mm. Excited by a 968 nm LD, the location of the strongest fluorescence peak was at 2796 nm. The upper (⁴I₁₁/₂) and lower (⁴I₃/₂) energy levels had lifetimes of 1.2 ms and 3.9 ms, respectively, indicating that the upper level life time was kept unchanged while the lower lifetime was significantly decreased during the ion exchange, which was favorable for improving the 2.7–3 µm laser performance. The maximum output pulse energy was 2.43 mJ using a 968 nm quasi-CW LD as the pump source. The corresponding peak power was 1.25 W and the optical–optical conversion efficiency reached 6.7%. The output laser spectrum ranged from 2.791 to 2.799 µm, where the center was at 2.796 µm and the spectrum linewidth (FWHM) was 4.5 nm. It was also found that strong gamma irradiation (100 Mrad) introduced negligible variation in laser power/energy, conversion efficiency, and beam quality, proving the good potential of Er:GYSGG as a new mid-infrared radiation-resistant laser material.
3.2. Laser Performance of Er,Pr:GYSGG Using Cr\(^{3+}\) as the Deactivator

An unavoidable problem for Er\(^{3+}\) doped laser gain media is the self-terminating effect for the \(^{4}I_{11/2} \rightarrow ^{4}I_{13/2}\) transition producing the 2.7–3 \(\mu\)m mid-infrared wavelength, which essentially originates from the shorter lifetime of the upper laser level compared to the lower level. Besides high-doping-induced upconversion (UP) and cross-relaxation (CR), co-doping with deactivator ions is recognized as an effective method to alleviate the self-terminating effect by reducing the lifetime of the lower laser level. Chen et al. used trivalent praseodymium ions (Pr\(^{3+}\)) as the deactivator and successfully grew high-quality Er:Pr:GYSGG crystals with the Czochralski method [9]. The energy transfer (ET) diagram between Er\(^{3+}\) and Pr\(^{3+}\) ions is shown in Figure 9. As there is an energy level (\(^{3}F_{4}\)) in Pr\(^{3+}\) that is adjacent to the \(^{4}I_{13/2}\) level of Er\(^{3+}\), co-doping with Pr\(^{3+}\) deactivated the terminal laser level. A few advantages, such as allowing laser operation at lower Er\(^{3+}\) ion doping level to reduce loss and \(^{4}I_{11/2}\) upconversion, and simplifying the dynamics through quasi-four-level operation, are provided through this process. The actual Er\(^{3+}\)→Pr\(^{3+}\) energy transfer efficiencies were 56.7% and 84.6% in ET\(_1\) and ET\(_2\), respectively. The upper level (\(^{4}I_{11/2}\)) and lower level (\(^{4}I_{13/2}\)) had lifetimes of 0.52 and 0.60 ms, respectively, resulting from the doping with Pr\(^{3+}\) ions. A maximum CW output power of 284 mW was produced from the Er:Pr:GYSGG laser with a slope efficiency of 17.4%. Pulses with a width of 0.5 ms and a repetition rate of 50 Hz were also generated in pulsed mode, with a maximum laser energy, peak power and slope efficiency of 2.4 mJ, 4.8 W, and 18.3%, respectively. By using a composite GYSGG/Er:Pr:GYSGG crystal to alleviate the thermal effects and optimizing the doping concentration of Er\(^{3+}\) and Pr\(^{3+}\) ions, the maximum CW output power was increased to 825 mW and single-pulse energy reached 3.65 mJ, corresponding to slope efficiencies of 19.2% and 22.7%, respectively [47]. Recently, Zhao et al. adopted the diode side-pumping scheme to pump Er:Pr:GYSGG, and realized a maximum output power of 8.66 W with a slope efficiency of 14.8% at a repetition rate of 125 Hz and pulse width of 200 \(\mu\)s. These impressive results indicate that Er:Pr:GYSGG crystals have great potential in high-power 2.79 \(\mu\)m laser generation by deactivation and LD side-pumping [48].

![Figure 9. Energy transfer diagram between Er\(^{3+}\) and Pr\(^{3+}\) ions in Er:Pr:GYSGG [9].](image)

3.3. Laser Performance of Cr,Er,Pr:GYSGG with a Wide Absorption Band for Lamp Pumping

Trivalent chromium ions (Cr\(^{3+}\)) can be used as a sensitizer in Er:Pr:GYSGG, making it possess extra wide absorption bands in the visible range, as shown in Figure 10. This property is crucial for improving the laser performance using flash-lamp pumping with a broad emission spectrum [10]. Luo et al. realized an output energy of 278 mJ at 2.79 \(\mu\)m with a Cr,Er:Pr:GYSGG crystal and a flash lamp. Benefiting from the good absorption for the pump energy, the electrical–optical and slope efficiency reached 0.6% and 0.7%, respectively. The maximum average output power was 2.9 W at a repetition rate of 60 Hz. A GYSGG/Cr,Er:Pr:GYSGG composite crystal was also used to alleviate the thermal effects, with which the maximum pulse energy was increased to 342.8 mJ at 5 Hz, corresponding to the electrical–optical and slope efficiencies of 0.86% and 1.08%, respectively [49]. The laser emitted from a composite crystal was also found to have better beam quality, fully demonstrating its obvious advantage in reducing thermal effects and improving laser performance.
However, with a Yb,Er,Ho:GYSGG crystal, 11Er for laser emission in the mid-infrared range. However, its laser performance is still far below that of 5 Hz, corresponding to an electrical–optical efficiency of 0.033% and slope efficiency of 11.6% and 13.1%, respectively. The laser threshold was significantly reduced to 81 mW as a result of the Ho3+ ion doping.

3.5. Mid-Infrared Laser Performance of Cr,Yb,Ho,Pr:GYSGG

Ho3+-doped laser crystals where Ho3+ works as the active ion exhibit a broadband fluorescence spectrum in the 2.7–3 μm range, which benefits the realization of multiple-wavelength or ultrashort laser generation [50]. However, there are problems with such crystals, in that the absorption is very low for Ho3+ lasers pumped by LD and flash lamp, and the lower laser energy level 5I7 has a much longer lifetime than that of the upper level 5I6, making laser generation very difficult. Recently, Zhang et al. developed a new crystal Cr,Yb,Ho,Pr:GYSGG, in which the Cr3+ and Yb3+ ions were used to sensitize the Ho3+ ions [51] and the Pr3+ ions acted as the deactivator to reduce the lifetime of the lower laser level (5I7). The average output power at 2.86 μm reached 257 mW with flash-lamp pumping at 5 Hz, corresponding to an electrical–optical efficiency of 0.033% and a slope efficiency of 0.04%. As a new gain medium with radiation resistance, the Cr,Yb,Ho,Pr:GYSGG crystal demonstrated the ability for laser emission in the mid-infrared range. However, its laser performance is still far below that of Er3+-doped lasers at present.
3.6. Mid-Infrared Laser Performance of Er$^{3+}$-Doped GYSGG: Summary

Table 4 summarizes the achieved laser performances of Er:GYSGG and sensitizer/deactivator-doped Er:GYSGG crystals. Most pump sources are LDs around 970 nm, except the Cr$^{3+}$-doped crystals, which possess wide absorption bands and are suitable for lamp pumping, as noted in the table. Both the overall conversion efficiency and maximum power/energy output are approaching the level of Er:YAG [52], Er:YLF [53], Er:YSGG [54], etc. Further research should focus on the Q-switching operation for high-peak-power output, as only free-running CW and pulsed Er$^{3+}$-doped GYSGG lasers have been reported. Power scaling can also incorporate cryogenic cooling to improve the thermal, spectroscopic, and laser properties of the laser crystals [55].

<table>
<thead>
<tr>
<th>Crystal</th>
<th>Wavelength (µm)</th>
<th>Pumping Scheme</th>
<th>Power/Energy</th>
<th>Efficiency</th>
<th>M$^2$ Factor</th>
</tr>
</thead>
<tbody>
<tr>
<td>Er:GYSGG [8]</td>
<td>2.796</td>
<td>End</td>
<td>348 mW</td>
<td>9.2%</td>
<td>1.94</td>
</tr>
<tr>
<td>Er,Pr:GYSGG [9]</td>
<td>2.79</td>
<td>End</td>
<td>284 mW</td>
<td>14.8%</td>
<td>1.72</td>
</tr>
<tr>
<td>GYSGG/Er,Pr:GYSGG [47]</td>
<td>2.79</td>
<td>End</td>
<td>825 mW</td>
<td>17%</td>
<td>1.7</td>
</tr>
<tr>
<td>Er/Pr:GYSGG [48]</td>
<td>2.79</td>
<td>Side</td>
<td>8.86 W</td>
<td>7.7%</td>
<td>7.5</td>
</tr>
<tr>
<td>Cr,Er,Pr:GYSGG [10]</td>
<td>2.79</td>
<td>Side</td>
<td>315.8 mJ</td>
<td>0.79%</td>
<td>—</td>
</tr>
<tr>
<td>GYSGG/Cr,Er,Pr:GYSGG [49]</td>
<td>2.79</td>
<td>Side</td>
<td>342.8 mJ</td>
<td>0.86%</td>
<td>3.7</td>
</tr>
<tr>
<td>Yb,Er,Ho:GYSGG [11]</td>
<td>2.79</td>
<td>End</td>
<td>411 mW</td>
<td>11.6%</td>
<td>1.97</td>
</tr>
</tbody>
</table>

1 Lamp pumping. 2 Electrical–optical conversion efficiency.

4. Nonlinear Optical Wavelength Extension Based on Nd:GYSGG and Er:GYSGG Lasers

With the development of growth technology for Nd:GYSGG, its laser performance can now match that of classical garnet laser crystals such as Nd:YAG. A significant advantage of Nd:GYSGG is that it is much easier to realize multi-wavelength operations due to Stark-level splitting, making it possible to generate various wavelengths through further nonlinear optical processes such as OPO, DFG, and stimulated Raman scattering (SRS), extending the wavelength range to the near-, mid-, and far-infrared regions.

Laser light at 1058.4 and 1061.5 nm produced by a dual-wavelength Nd:GYSGG laser has been used as the fundamental wavelengths to pump noncritically phase-matched intracavity optical parametric oscillators (IOPOs), generating eye-safe lasers in the 1.5–1.6 µm band based on nonlinear crystals KTP and KTA. Using a KTA crystal, two signal wavelengths at 1525.1 and 1531.2 nm were produced simultaneously [56], with a maximum average output power, single-pulse energy, and peak power of 296 mW, 2.96 µJ, and 6.4 kW, respectively. For KTP associated with a specially designed folded cavity for mode-matching and thermal stability, dual-signal operation at 1562.1 and 1567.4 nm was achieved [57]. The average power, single-pulse energy and peak power increased to 750 mW, 75 µJ, and 22.7 kW, respectively. As the OPO wavelengths coincide with the absorption bands of gases such as C$_2$H$_2$, CO, and CO$_2$, such dual-wavelength OPOs can be good laser source options in differential absorption lidar (DIAL) for remote gas sensing.

Besides second-order nonlinear devices, third-order nonlinear effects also have been effectively achieved by pumping with an Nd:GYSGG laser. Jiang et al. demonstrated a 1.5 µm eye-safe laser via SRS using an $a$-cut YVO$_4$–Nd:YVO$_4$ crystal as the nonlinear medium and pumped inside a 1321/1336 nm dual-wavelength Nd:GYSGG laser cavity [58]. A schematic and the output spectrum are shown in Figure 12. In-band pumping at 882.9 nm was employed to alleviate the serious thermal lensing effect and enhance the eye-safe laser output power. When the absorbed pump power was 23.2 W, a total Stokes output power of 2.11 W was achieved with a simultaneous dual-wavelength at 1497 nm and 1516 nm. The pulse repetition rate was 23 kHz and the corresponding conversion efficiency was 9.1%. 
DFG is an important approach for terahertz-wave generation, in which a dual-wavelength laser plays the main role [59]. Since various simultaneous dual-wavelength laser pulses in Nd:GYSGG such as 1053/1058, 1058/1061, 1321/1336, and 1562/1567 nm, have been realized to provide frequency intervals covering 0.6 THz to 2.5 THz, terahertz waves can be extracted using nonlinear crystals, such as GaSe, ZnGeP$_2$, DAST, etc. The prerequisite is that the relative intensity of the two laser lines of the dual-wavelength laser should be sufficiently stable.

Nonlinear frequency conversion based on mid-infrared Er$^{3+}$-doped GYSGG lasers, which has not yet been achieved, also has great potential for pumping infrared nonlinear crystals to generate 3–5 µm and 8–12 µm mid-infrared lasers. On the one hand, the quantum efficiency is much higher when using 3 µm pumping than with pumping around 1.06 µm. On the other hand, some nonlinear crystals, such as GaAs and ZnGeP$_2$, are non-transparent in the near-infrared range, and require mid-infrared pumping. Considering the remarkable radiation-resistant characteristics of Er$^{3+}$-doped GYSGG, it is believed that lasers using this material will be popular in nonlinear frequency conversion once the efficiency is improved, especially in high-radiation space applications.

5. Conclusions

In conclusion, this paper gives a review of the performances of Nd$^{3+}$- and Er$^{3+}$-doped lasers based on a new but promising host material—GYSGG. The development of Nd:GYSGG lasers delivering wavelengths in the ranges of 0.9, 1.06, 1.1, 1.3, and 1.4 µm, and with operation modes covering CW, Q-switching, and mode-locking is elaborated. Some typical applications of Nd:GYSGG lasers are also given, in pumping nonlinear frequency conversion for wavelength extension to longer wavelengths through OPO and SRS. A distinctive feature of these lasers is that simultaneous dual- or multiple-wavelength operation is easily accessible, which is of great interest in applications of precision measurement, spectroscopy, remote sensing, frequency conversion to terahertz, and so on. Er:GYSGG, which can directly give 2.7–3 µm laser radiation, has been proven to be a good mid-infrared laser gain medium for both LD and lamp pumping. To overcome the self-terminating effect in Er:GYSGG, co-doping of Yb$^{3+}$, Cr$^{3+}$, Pr$^{3+}$, Ho$^{3+}$, etc. was studied as sensitizer and deactivator ions, in which great progress has been made during the past few years. The performances of GYSGG lasers doped with both Nd$^{3+}$ and Er$^{3+}$ ions have reached those of the state-of-the-art conventional garnet host materials YAG, GGG, YSGG, etc. Considering that Nd$^{3+}$- and Er$^{3+}$-doped GYSGG crystals possess extraordinary radiation-resistant characteristics compared to Nd/Er:YAG, etc., it is expected that this review will help researchers to learn about such crystals and promote their commercialization and application in the near future.

**Funding:** This work was funded by the National Natural Science Foundation of China (Grant No. 61675146) and the Natural Science Foundation of Tianjin City (18JCJQJC16700).

**Conflicts of Interest:** The author declares no conflict of interest.
References


30. Dun, Y.; Feng, C.; Chen, X.; Li, P.; Wang, Q.; Song, T. Gold nanorods based passively Q-switched solid-state laser at 1111.4 nm wavelength. *Optik* 2017, 147, 360–365. [CrossRef]


33. Song, T.; Li, P.; Chen, X.; Ma, B.; Dun, Y. Passively Q-switched Nd:GYSGG laser operating at 1.3 μm with V:YAG as saturable absorber. *Optik* 2016, 127, 10621–10625. [CrossRef]


